

Peer Review

Review of: "Negative Capacitance Effect at the Interface Between Si Wafers with Undulating Surfaces"

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1. The abstract section does not reflect the work reported by the authors. It should be clear and concise.
2. To demonstrate the Negative Capacitance effect, authors should produce the Polarization (Hysteresis curve).
3. A temperature study on two different samples and variation in the characteristics might be interesting.

Declarations

Potential competing interests: No potential competing interests to declare.